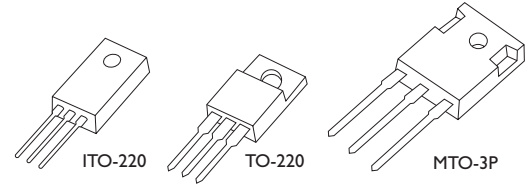


HIGH VOLTAGE • HIGH SPEED SWITCHING TRANSISTORS

HDT series

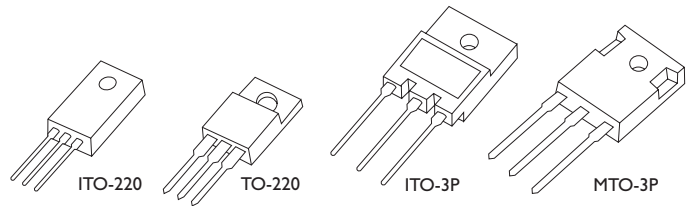
Bipolar transistors (NPN)



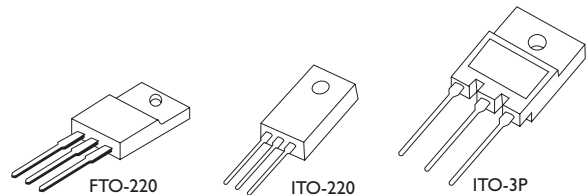
Type No.	Absolute Maximum Ratings								Electrical Characteristics									Outline	
	V _{RM}	V _{CEO}	V _{EB0}	I _C	I _B	P _T	T _{stg}	T _J	V _{CEO} (sus) (min)	h _{FE}	V _{CE} (sat) (max)	V _{BE} (sat) (max)	θ _{JC}	f _r	t _{on}	t _s	t _f		
	[V]	[V]	[V]	[A]	[A]	[W]	[°C]	[°C]	[V]	(min)	[V]	[V]	[°C/W]	[MHz]	[μs]	[μs]	[μs]	Package	Figure
2SC4310	900	800	7	6	3	50	-55	150	800	7	1.5	2.5	2.5	7	0.5	3	0.5	TO-220	80-3
4311						40							3.1					ITO-220	82-4
4312						80							1.56					MTO-3P	86-2
4313				10	4	100							1.25						
4314				15	6	130							0.96						

HFX series

Bipolar transistors (NPN)



Type No.	Absolute Maximum Ratings								Electrical Characteristics										Outline	
	V _{RM}	V _{CEO}	V _{EB0}	I _C	I _B	P _T	T _{stg}	T _J	V _{CEO} (sus) (min)	h _{FE}	V _{CE} (sat) (max)	V _{BE} (sat) (max)	θ _{JC}	f _T	t _{ON}	t _S	t _F			
	[V]	[V]	[V]	[A]	[A]	[W]	[°C]	[°C]	[V]	(min)	[V]	[V]	[°C/W]	[MHz]	[μs]	[μs]	[μs]	Package	Figure	
2SC4230	1200	800	7	2	1	50	-55	150	800	8	1	1.5	2.5	8	0.5	3.5	0.3	TO-220	80-3	
4231						30							4.16					ITO-220	82-4	
4232						70							1.7					MTO-3P	86-2	
4233				3	1	60							2.08					TO-220	80-3	
4234						45							2.77					ITO-220	82-4	
4235						80							1.56					MTO-3P	86-2	
4236				6	3	100							1.25							
4237				10	4	150							0.83							
4583				3	1	50							2.5					ITO-3P	88-3	
4584				6	3	65							1.92							
4585				10	4	85							1.47							



Switching Transistors for Lighting Equipment

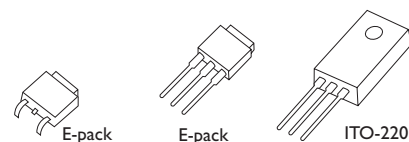
Bipolar transistors (NPN)

Type No.	Absolute Maximum Ratings								Electrical Characteristics										Outline	
	V _{RM}	V _{CEO}	V _{EB0}	I _C	I _B	P _T	T _{stg}	T _J	V _{CEO} (sus) (min)	h _{FE} (min)	V _{CE} (sat) (max)	V _{BE} (sat) (max)	θ _{Jc} (max)	f _r (typ)	t _{on} (max)	t _s (max)	t _f (max)			
	[V]	[V]	[V]	[A]	[A]	[W]	[°C]	[°C]	[V]	(min)	[V]	[V]	[°C/W]	[MHz]	[μs]	[μs]	[μs]	Package	Figure	
2SC4940	1200	550	7	4	2	30	−55	150	550	10	1	1.5	4.16	10	0.8	3.0	0.3	ITO-220	82-4	
4941	1500	800		6	3	65	150		800	15	0.5		1.92	8	0.5	3.5		ITO-3P	88-3	
5382	1200	550	9			40	150		550	10	1		3.13	—	1.3	4.0		FTO-220	84-3	

LOW SATURATION VOLTAGE SWITCHING TRANSISTORS

LSV series

Bipolar transistors

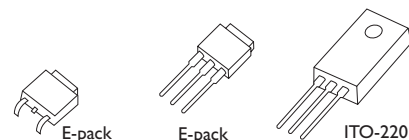


Type No.	Absolute Maximum Ratings								Electrical Characteristics									Outline	
	V _{CEO}	V _{CEO}	V _{EB0}	I _C	I _B	P _T	T _{stg}	T _J	V _{CEO} (sus) (min)	h _{FE} (min)	V _{CE} (sat) (max)	V _{BE} (sat) (max)	θ _{JC} (max)	f _r (typ)	t _{on} (max)	t _s (max)	t _f (max)		
	[V]	[V]	[V]	[A]	[A]	[W]	[°C]	[°C]	[V]		[V]	[V]	[°C/W]	[MHz]	[μs]	[μs]	[μs]	Package	Figure
2SA1795	-60	-40	-7	-5	-1.5	10	-55 150	150	-40	70	-0.3	-1.2	12.5	50	0.3	1.5	0.5	E-pack	*I
1796				-7									12.5						
1679				-5									5						
1598				-7		25							5						
1599				-10		5													
1600				-12	30	4.16													
1601				-15	45	2.77													
2SC4668	60	40	7	7	1.5	10	-55 150	150	40	70	0.3	1.2	12.5	50	0.3	1.5	0.5	E-pack	*I
4669				10									12.5						
4148				7									5						
4149				10		25							5						
4150				12		5													
4151				15	30	4.16													
4876				30	4	45							100					2.78	

*I: Leaded package - Fig. 78-3; SMD package - Fig. 77-3

HSV series

Bipolar transistors



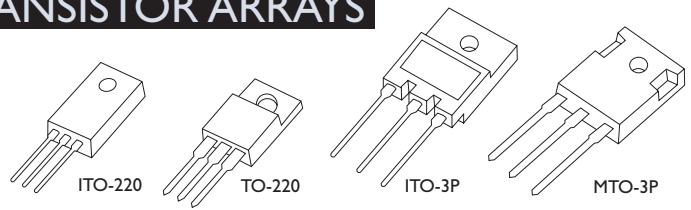
Type No.	Absolute Maximum Ratings								Electrical Characteristics									Outline	
	V _{CEO}	V _{CEO}	V _{EB0}	I _C	I _B	P _T	T _{stg}	T _J	V _{CEO} (sus) (min)	h _{FE} (min)	V _{CE} (sat) (max)	V _{BE} (sat) (max)	θ _{JC} (max)	f _r (typ)	t _{on} (max)	t _s (max)	t _f (max)		
	[V]	[V]	[V]	[A]	[A]	[W]	[°C]	[°C]	[V]		[V]	[V]	[°C/W]	[MHz]	[μs]	[μs]	[μs]	Package	Figure
2SA1876	-80	-80	-7	-3	-1	10	-55 150	150	-80	70	-0.3	-1.2	12.5	50	0.3	1.5	0.2	E-pack	*1
1877				-5	-1.5	25							5					ITO-220	82-4
1878				-7															
1879				-10															
1880																			
2SC4978	100	80	7	3	1	10	-55 150	150	80	70	0.3	1.2	12.5	50	0.3	1.5	0.2	E-pack	*1
4979				5	1.5	25							5					ITO-220	82-4
4980				7															
4981				10															
4982																			

*I: Leaded package - Fig. 78-3; SMD package - Fig. 77-3

DARLINGTON TRANSISTORS & TRANSISTOR ARRAYS

Darlington Power Transistors

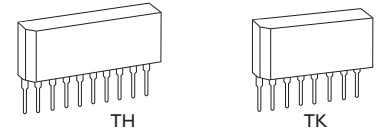
Bipolar transistors



Type No.	Absolute Maximum Ratings								Electrical Characteristics										Outline										
	V _{CB0}	V _{CE0}	V _{EB0}	I _C	I _B	P _T	T _{stg}	T _J	V _{CE0} (sus) (min)	h _{FE} (min)	V _{CE} (sat) (max)	V _{BE} (sat) (max)	θ _{Jc} (max)	f _T (typ)	t _{on} (max)	t _s (max)	t _f (max)												
	[V]	[V]	[V]	[A]	[A]	[W]	[°C]	[°C]	[V]	(min)	[V]	[V]	[°C/W]	[MHz]	[μs]	[μs]	[μs]	Package	Figure										
2SD1022	100	100	7	5	0.5	30	-55 ~ 150	150	—	1500	1.5	2	4.17	20	2	5	3	TO-220	80-3										
1023	200	200														8	5												
1024	100	100	7	8	0.5	50										150	—			1500	1.5	2	2.5	20	2	5	3		
1025	200	200																								8	5		
1026	100	100	7	15	1	100		150	—	1500	1.5	2	1.25	20	2	5	3	MTO-3P	86-2										
1027	200	200														8	5			5	ITO-3P	88-3							
2196	200	200											12	5															
1788	100	100	7	±4	0.3	25	-55 ~ 150	150	—	1500	1.5	2	5.0	20	2	12	5	ITO-220	82-4										
1789	200	200																											
1790	60±10	60±10	7	7	0.5	30														150	—	1500	1.5	2	4.17	20	2	12	5
1791	100	100																											
1792	200	200	7	10	0.5	50		150	—	1500	1.5	2	2.5	20	2	12	5												
1793	100	100																											
1794	200	200	12	10	0.5	50		150	400	150	1.5	2	2.5	10	2	15	15												
1795	500	400																											
2SB1282	-100	-100	-7	±4	-0.3	25	-55 ~ 150	150	—	1500	-1.5	-2	5	20	1	4	2	ITO-220	82-4										
1283				-7	-0.5	30							4.16																
1284				-10	-0.8	35							3.57																
1285				-15	-1	100							1.25							ITO-3P	86-2								
1448						65							1.92									ITO-3P	88-3						

Transistor Arrays

Bipolar transistors Arrays



Type No.	Absolute Maximum Ratings								Electrical Characteristics								Remarks	Outline						
	V _{CB0}	V _{CE0}	V _{EB0}	I _C	I _B	P _T	T _{stg}	T _J	h _{FE}	V _{CE} (sat)	V _{BE} (sat)	θ _{JA}	t _{on}	t _s	t _f	Package		Figure						
	[V]	[V]	[V]	[A]	[A]	[W]	[°C]	[°C]	(min)	[V]	[V]	[°C/W]	[μs]	[μs]	[μs]									
TH3L10	100	100	7	±3	0.3	3.5	-55~150	150	1500	1.5	2	35	2	8	3	NPNX4	TH	65						
3L20	200	200								±1.5	±2					NPNX2, PNPX2								
3C10	±100	±100	±7		±0.3					±1.5	±2					PNPX4								
3J10	-100	-100	-7		-0.3					-1.5	-2													
3L10Z*	60 ^{±10}	60 ^{±10}	7	5	0.3	3.5						50	2	8	3	NPNX4	TK	66						
5L10	100	100																						
5L20	200	200	7	±3	0.3	2.5										NPNX3								
TK3L10	100	100																						
3L20	200	200	7	5	0.3	2.5										PNPX3								
3J10	-100	-100														-7								
3L10Z*	60 ^{±10}	60 ^{±10}	7	5	0.5	2.5										NPNX3								
5L10	100	100																						
5L20	200	200	7	±5	±1.5	3.5						70	±0.3	±1.2	35.7	0.3	2	0.5	NPNX2, PNPX2	TH	65			
TH5P4	±60	±40																				±7	±5	±1.5

※: With zener diode between collector and base